



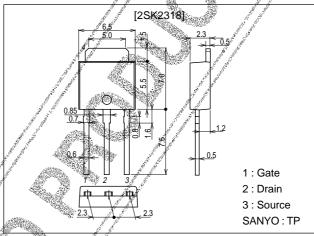
Ultrahigh-Speed Switching Applications

Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · 2.5V drive.

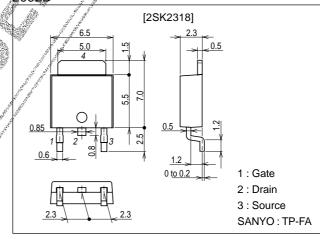
Package Dimensions

unit:mm 2083B



unit:mm

2092B



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Specifications

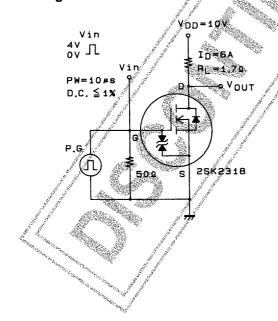
Absolute Maximum Ratings at Ta = 25°C

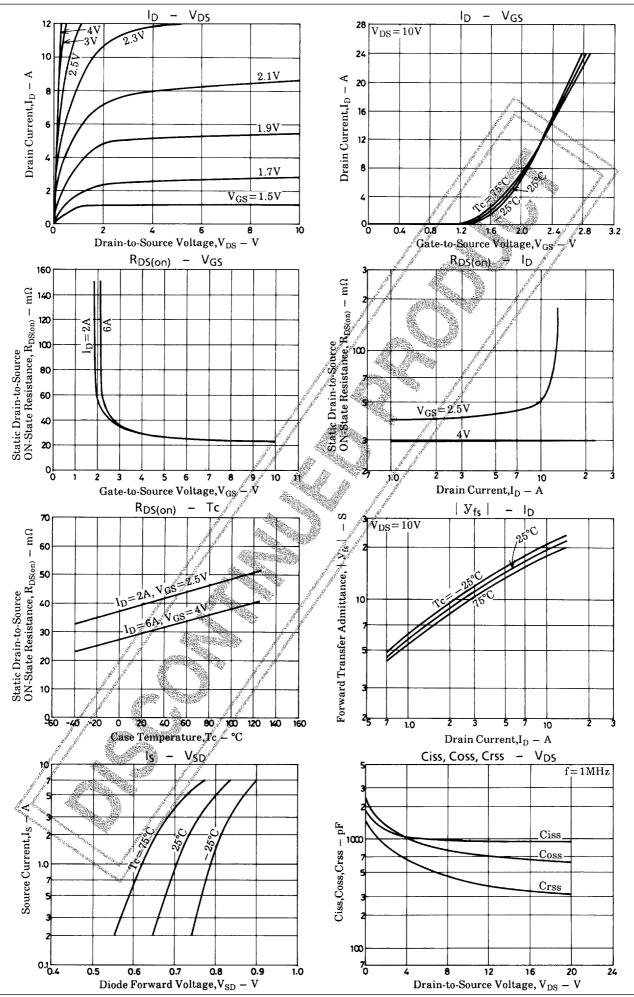
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		20	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	I _D		12	А
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	48	А
Allowable Power Dissipation	PD	1	30,	W
		Tc=25°C	1	W
Channel Temperature	Tch	3.9	, 150	∕″C
Storage Temperature	Tstg	11	-55 to +150	*°C
Electrical Characteristics at Ta = 25°C				

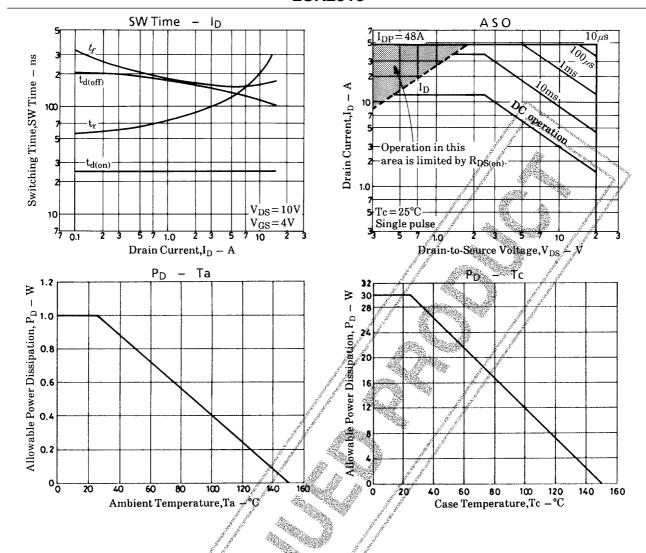
Electrical Characteristics at Ta = 25°C

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Parameter	Symbol	Conditions	min	Ratings typ	max	Unit
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =1mA, V _{GS} =0	20	and the same of th		V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =16V, V _{GS} =0	ئني	J. Market	100	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0	ا او المحافظة	S. A. T.	±10	μΑ
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	₃ 0.4		1.4	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =6A	<i>f</i> / 10	14		S
Static Drain-to-Source ON-State Resistance	R _{DS(on)}	I _D =6A, V _{GS} =4V		30	38	mΩ
Static Dialit-to-Source Oiv-State Resistance	R _{DS(on)}	I _D =2A, V _{GS} =2,5V		40	58	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=¶MHz		1000		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		750		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		400		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit		25		ns
Rise Time	t _r	See specified Test Circuit		135		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		135		ns
Fall Time	t _f	See specified Test Circuit		150		ns
Diode Forward Voltage	V _{SD}	I _S =8A,V _{GS} =0		1.0	1.2	V

Switching Time Test Circuit







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